

### FEATURES

- Fast switching
- Low on-resistance
- Low gate charge
- 100% Single Pulse Avalanche Energy Test

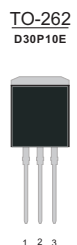
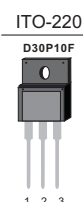
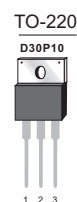
Product Summary			
$V_{DS}$	$R_{DS(on)}$ (m $\Omega$ ) Typ	$I_D$ (A)	$Q_g$ (Typ)
-100V	35@ -10V	-30	90nc

### MECHANICAL DATA

- Case: TO-220\ITO-220\TO-263\TO-262\TO-251\TO-252 Package

### Ordering Information

Part No.	Package Type	Package	Quality(box)
D30P10	TO-220	Tube	1000
D30P10F	ITO-220	Tube	1000
D30P10D	TO-263	Tape & Reel	800
D30P10E	TO-262	Tube	1000
D30P10M	TO-252	Tape & Reel	2500
D30P10N	TO-251	Tube	1000



Pin Definition:

1. Gate
2. Drain
3. Source

### Block Diagram

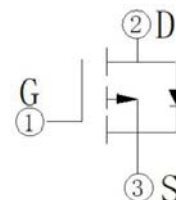


Table1 Absolute Maximum Ratings ( $T_C=25^\circ\text{C}$ , unless otherwise specified)

Parameter	Symbol	TO-220/TO-263/TO-262 TO-251/TO-252	ITO-220	Unit
Drain-Source Voltage	$V_{DS}$	-100		V
Gate-Source Voltage	$V_{GS}$	$\pm 20$		V
Continuous Drain Current	$I_D$	-30		A
		-21		
Pulsed Drain Current (Note 1)	$I_{DM}$	-120		A
Single Pulse Avalanche Energy(Note 2)	$E_{AS}$	317		mJ
Avalanche Current(Note 1)	$I_{AR}$	2		A
Power Dissipation $T_C=25^\circ\text{C}$	$P_D$	120	48	W
Operating Junction and Storage Temperature	$T_J/T_{STG}$	-55 ~ +150		$^\circ\text{C}$
Maximum Temperature for soldering	$T_L$	300		$^\circ\text{C}$

## D30P10 Series

Table 2. Thermal Characteristics

Parameter	Symbol	TO-220/TO-263/TO-262 TO-251/TO-252	ITO-220	Unit
Thermal resistance Junction to Ambient	$R_{\theta JA}$	62	62	$^{\circ}\text{C/W}$
Thermal resistance Junction to Case	$R_{\theta JC}$	1.04	2.6	$^{\circ}\text{C/W}$

Table 3. Electrical Characteristics ( $T_J=25^{\circ}\text{C}$ , unless otherwise specified)

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Off Characteristics							
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250μA	-100	--	--	V
Drain-Source Leakage Current		I <sub>DSS</sub>	V <sub>DS</sub> =-100V,V <sub>GS</sub> =0V	--	--	-1	μA
Gate- Source Leakage Current	Forward	I <sub>GSS</sub>	V <sub>GS</sub> =20V,V <sub>DS</sub> =0V	--	--	100	nA
	Reverse		V <sub>GS</sub> =-20V,V <sub>DS</sub> =0V	--	--	-100	nA
On Characteristics(Note 4)							
Gate Threshold Voltage		V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-1	--	-3	V
Static Drain-Source On-State Resistance		R <sub>DS(ON)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-15A	--	35	51	mΩ
Dynamic Characteristics(Note 5)							
Input Capacitance		C <sub>ISS</sub>	V <sub>DS</sub> =-25V,V <sub>GS</sub> =0V,f=1MHz	--	2700	--	pF
Output Capacitance		C <sub>OSS</sub>		--	790	--	pF
Reverse Transfer Capacitance		C <sub>RSS</sub>		--	450	--	pF
Switching Characteristics (Note 5)							
Turn-On Delay Time		t <sub>d (on)</sub>	V <sub>DD</sub> =-50V,I <sub>D</sub> =-15A,V <sub>GS</sub> =-10V R <sub>G</sub> =9.1Ω	--	17	--	ns
Turn-On Rise Time		t <sub>tr</sub>		--	80	--	ns
Turn-Off Delay Time		t <sub>d (off)</sub>		--	45	--	ns
Turn-Off Fall Time		t <sub>f</sub>		--	65	--	ns
Total Gate Charge		Q <sub>G</sub>	V <sub>DD</sub> =-50V,I <sub>D</sub> =-15A, V <sub>GS</sub> =-10V	--	90	--	nC
Gate-Source Charge		Q <sub>GS</sub>		--	15	--	nC
Gate-Drain Charge		Q <sub>GD</sub>		--	35	--	nC
Drain-Source Diode Characteristics and Maximum Ratings							
Drain-Source Diode Forward Voltage		V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =-30A	--	--	-1.5	V
Maximum Continuous Drain-Source Diode Forward Current (Note 3)		I <sub>S</sub>		--	--	-30	A
Reverse Recovery Time		t <sub>rr</sub>	V <sub>GS</sub> =0V, I <sub>F</sub> =-15A	--	90	--	ns
Reverse Recovery Charge		Q <sub>RR</sub>	dI <sub>F</sub> /dt=100A/μs (Note 1)	--	70	--	nC

Notes : 1 Repetitive Rating:Pulse width limited by maximum junction temperature

2  $L=0.5\text{mH}$   $I_D=-35.6A, V_{DD}=-50V, V_{GATE}=-100V$ , Starting  $T_J=25^{\circ}\text{C}$

3 Surface mounted on FR4 Board,  $t \leq 10\text{sec}$

4 Pulse Test: Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$

5 Guaranteed by design, not subject to production

Typical characteristics Diagrams

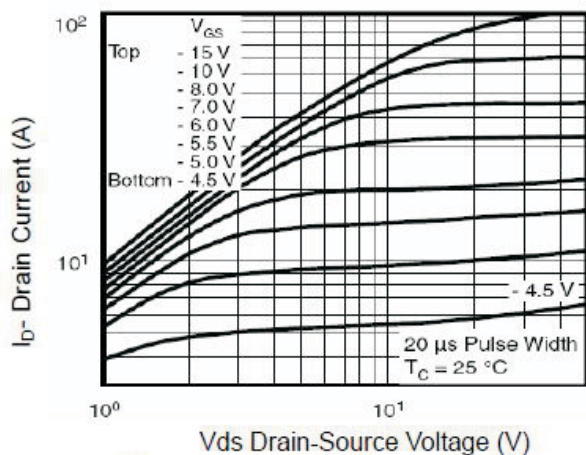


Figure 1 Output Characteristics

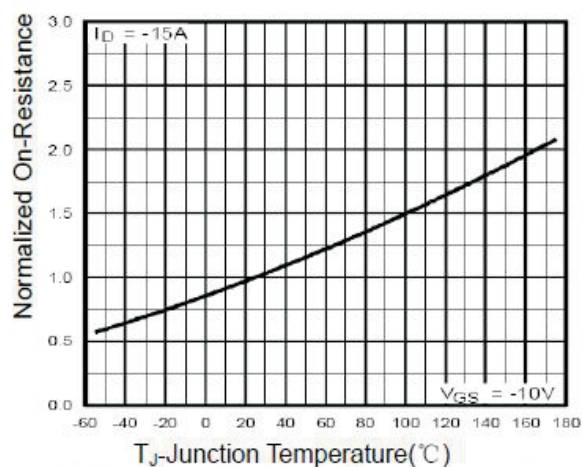


Figure 4 Rdson-Junction Temperature

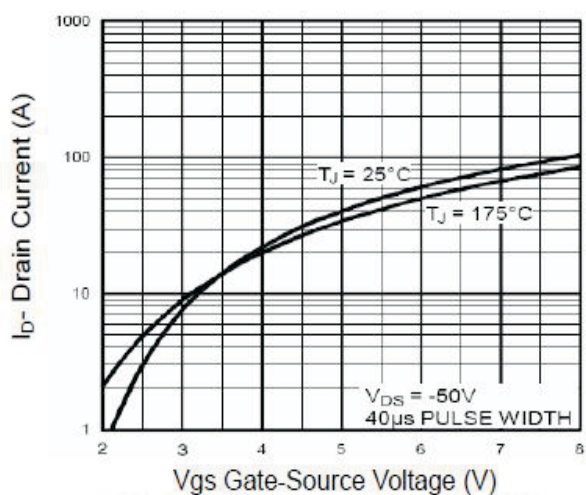


Figure 2 Transfer Characteristics

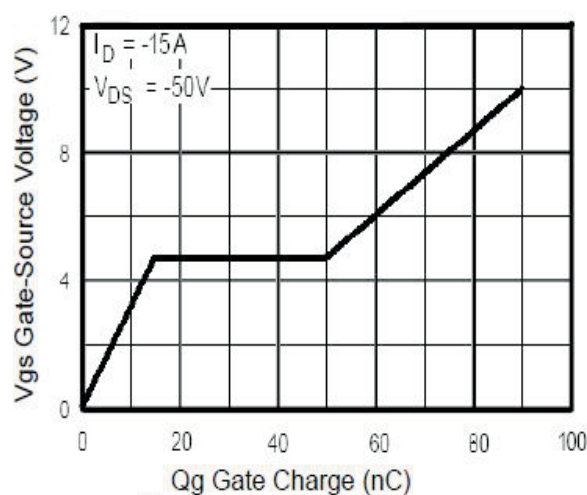


Figure 5 Gate Charge

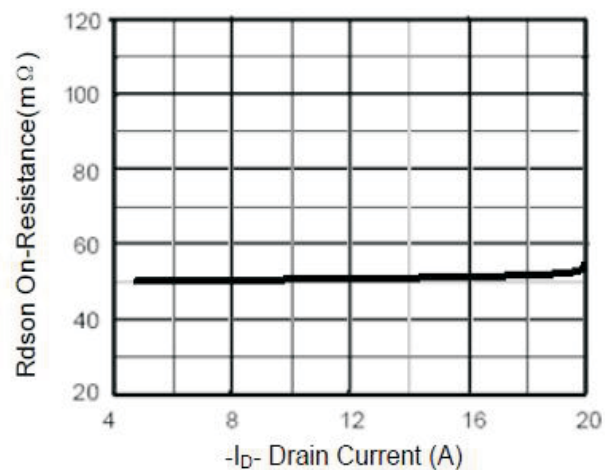


Figure 3 Rdson- Drain Current

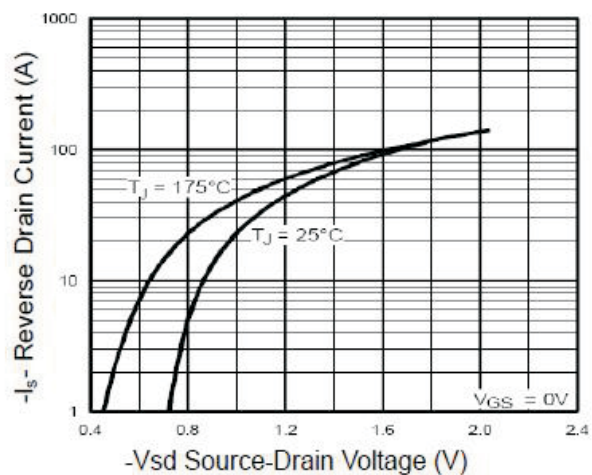


Figure 6 Source- Drain Diode Forward

Typical characteristics Diagrams

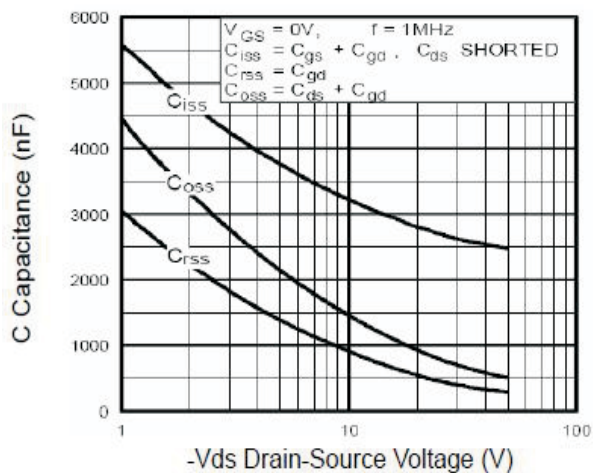


Figure 7 Capacitance vs Vds

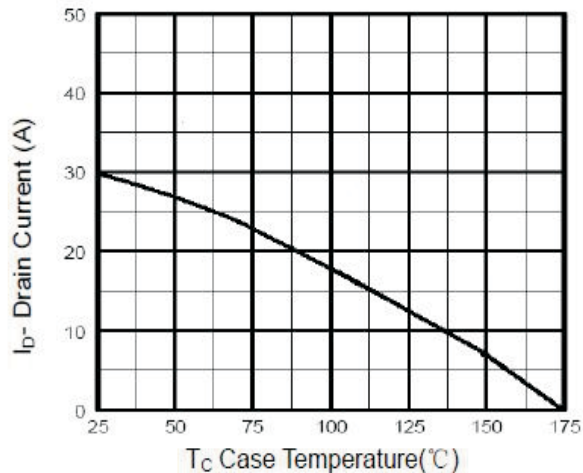


Figure 9 Drain Current vs Case Temperature

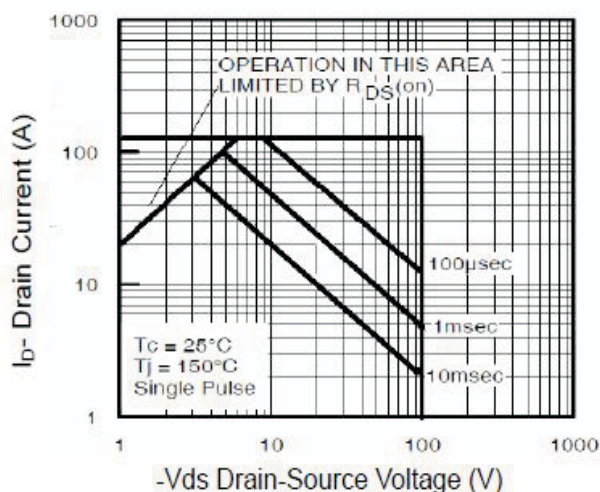


Figure 8 Safe Operation Area

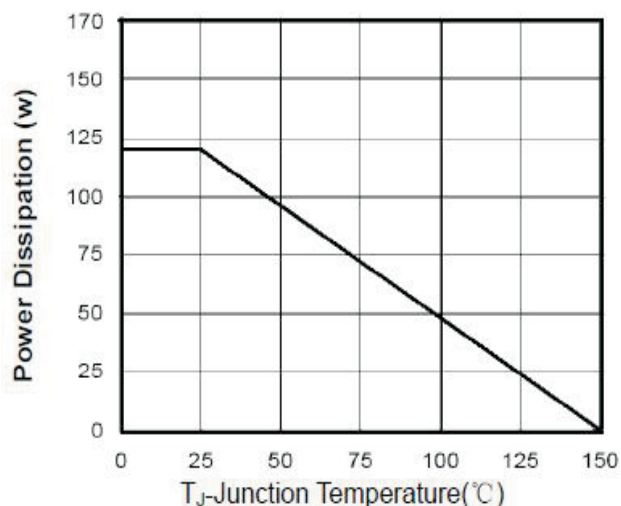


Figure 10 Power De-rating

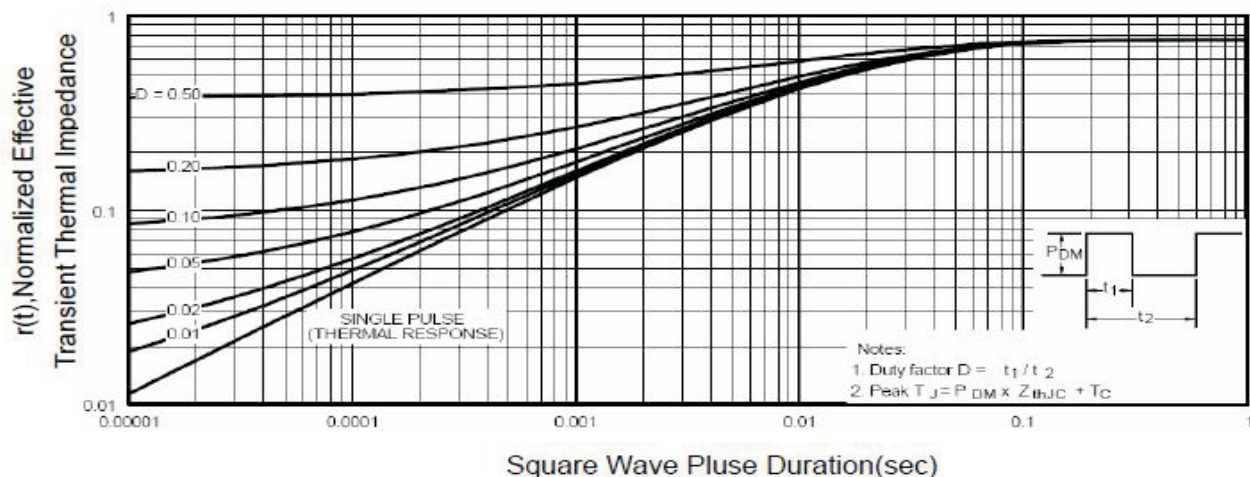
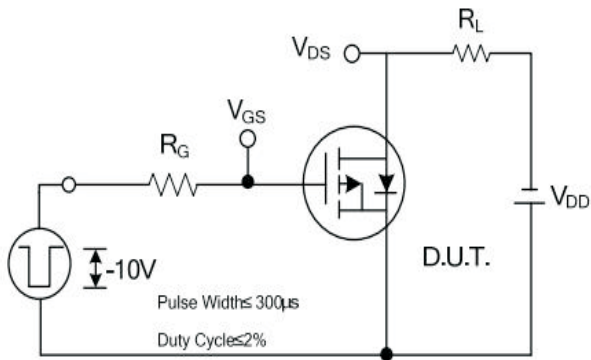


Figure 11 Normalized Maximum Transient Thermal Impedance

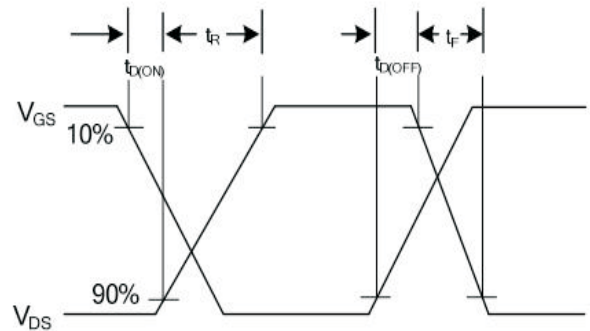


## D30P10 Series

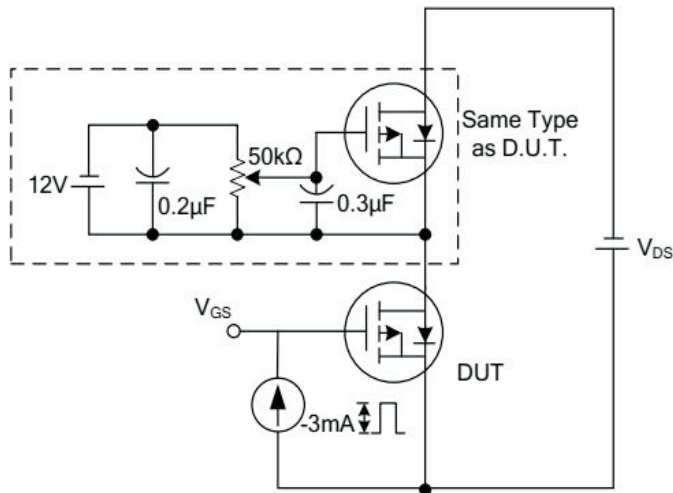
### Typical Test Circuit and Waveform



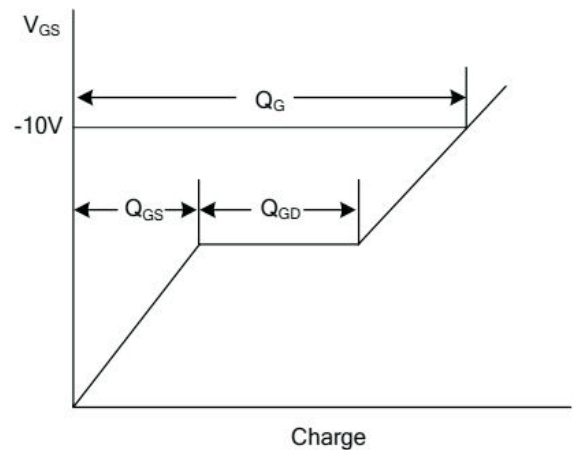
**Switching Test Circuit**



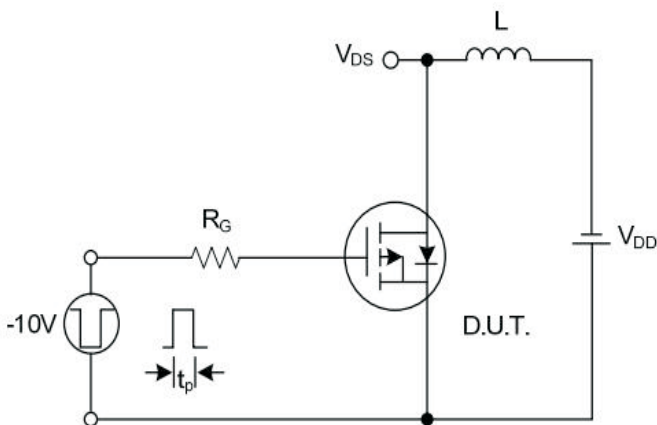
**Switching Waveforms**



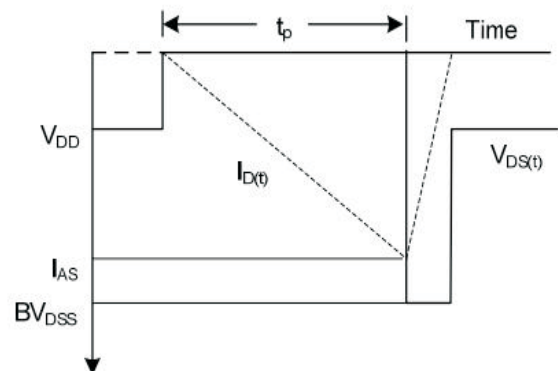
**Gate Charge Test Circuit**



**Gate Charge Waveform**

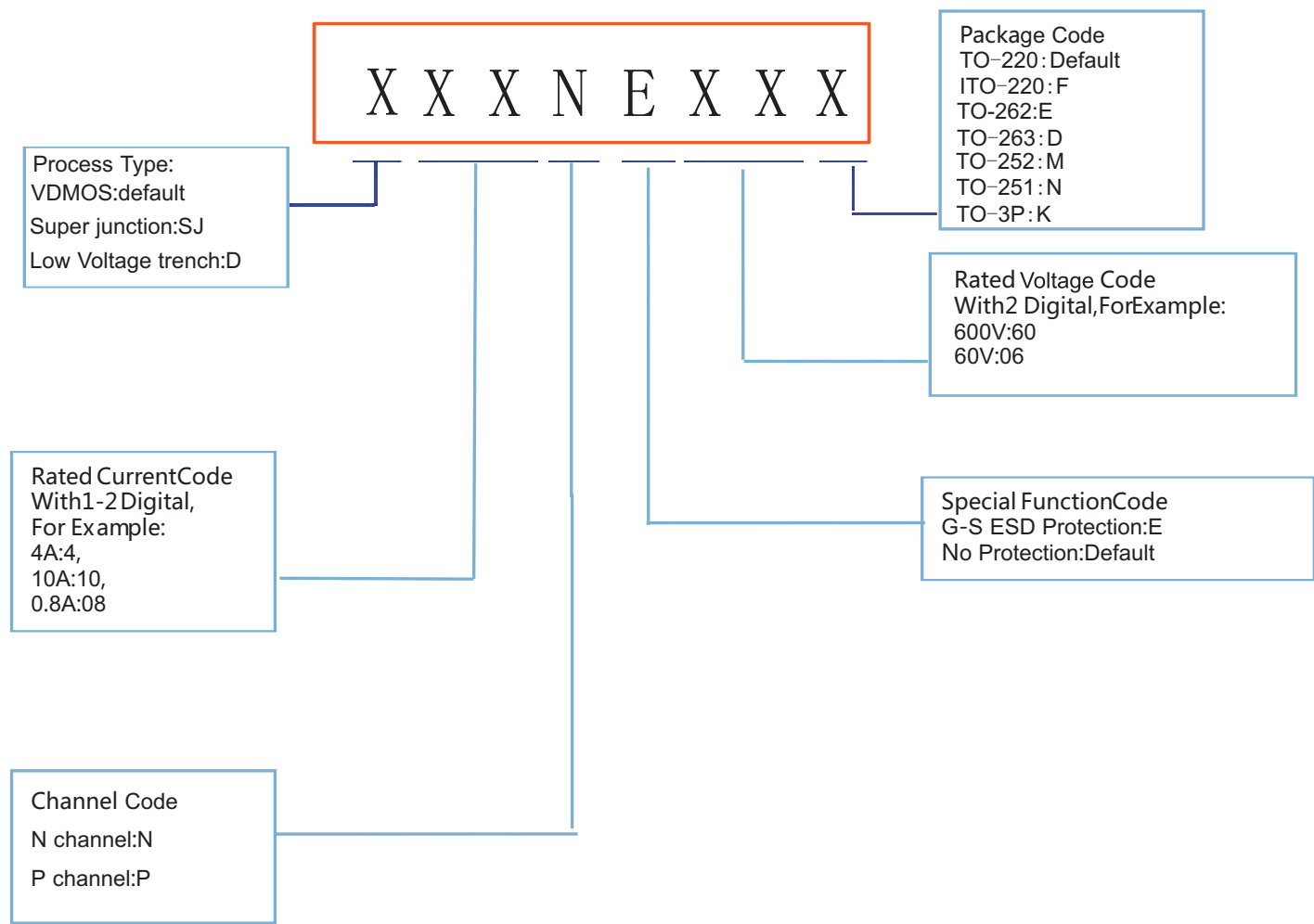


**Unclamped Inductive Switching Test Circuit**



**Unclamped Inductive Switching Waveforms**

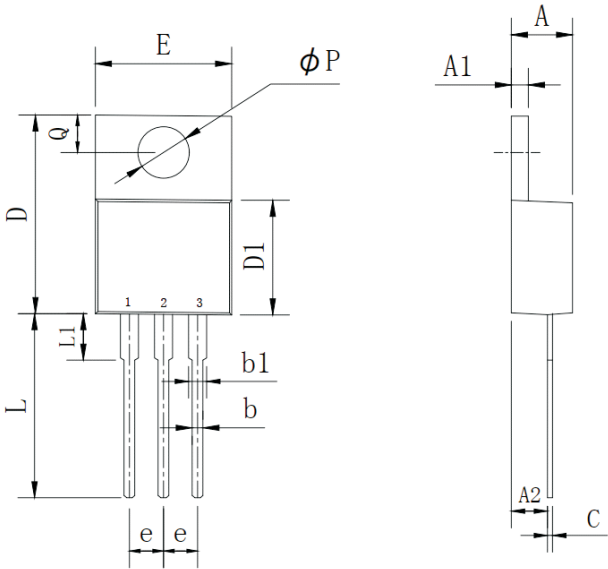
Product Names Rules



# D30P10 Series

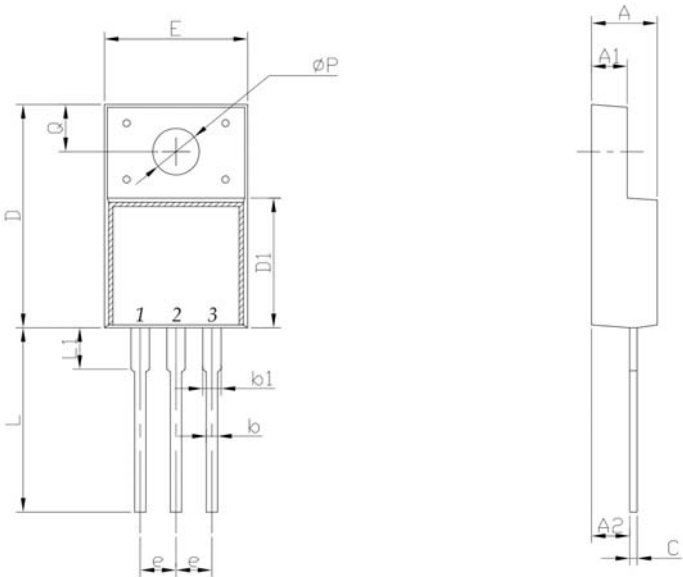
## Dimensions

### TO-220 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.25	4.87	0.167	0.192
A1	1.07	1.47	0.042	0.058
A2	2.03	2.92	0.080	0.115
b	0.51	1.11	0.020	0.044
b1	0.97	1.6	0.038	0.063
C	0.3	0.7	0.012	0.028
D	14.6	15.9	0.575	0.626
D1	8.04	9.3	0.317	0.366
E	9.57	10.57	0.377	0.416
e	2.34	2.74	0.092	0.108
L	12.58	14.3	0.495	0.563
L1	2.8	4.2	0.110	0.165
P	3.4	4.14	0.134	0.163
Q	2.45	3	0.096	0.118

### ITO-220 PACKAGE OUTLINE DIMENSIONS

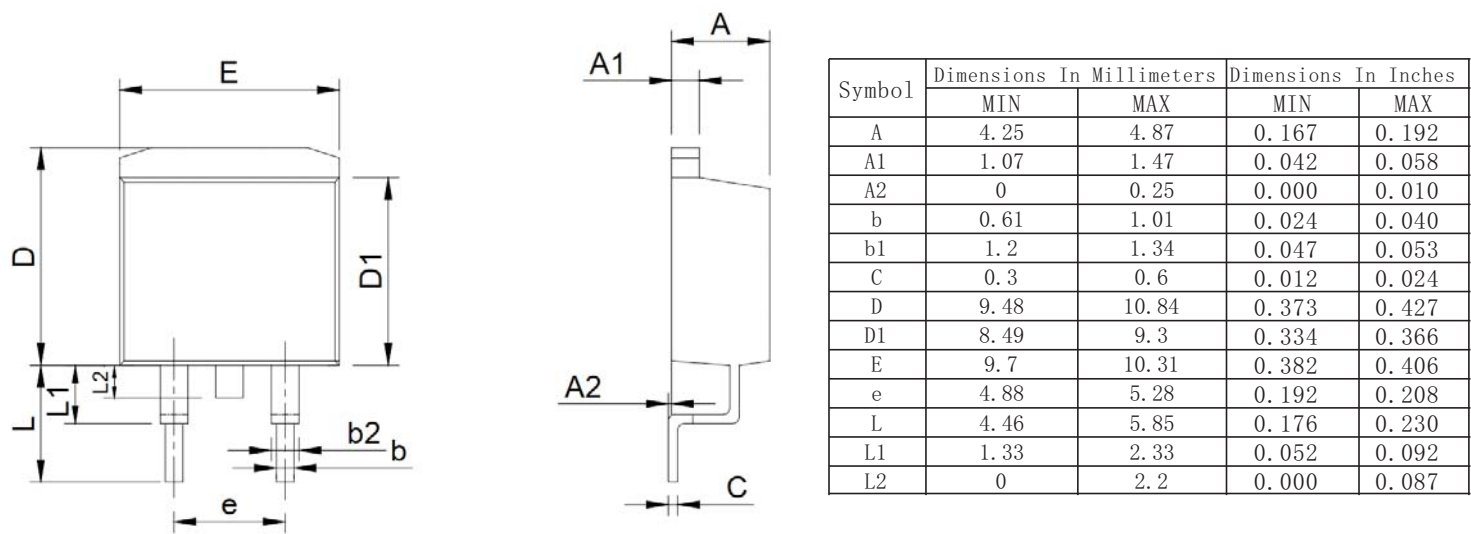


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	4.24	4.9	0.167	0.193
A1	2.3	2.92	0.091	0.115
A2	2.61	2.81	0.103	0.111
b	0.3	1	0.012	0.039
b1	0.9	1.55	0.035	0.061
C	0.3	0.7	0.012	0.028
D	14.5	16.36	0.571	0.644
D1	8.8	9.41	0.346	0.370
E	9.5	10.5	0.374	0.413
e	2.3	2.75	0.091	0.108
L	12.6	14	0.496	0.551
L1	2.45	4.3	0.096	0.169
P	2.9	3.8	0.114	0.150
Q	2.5	3.55	0.098	0.140

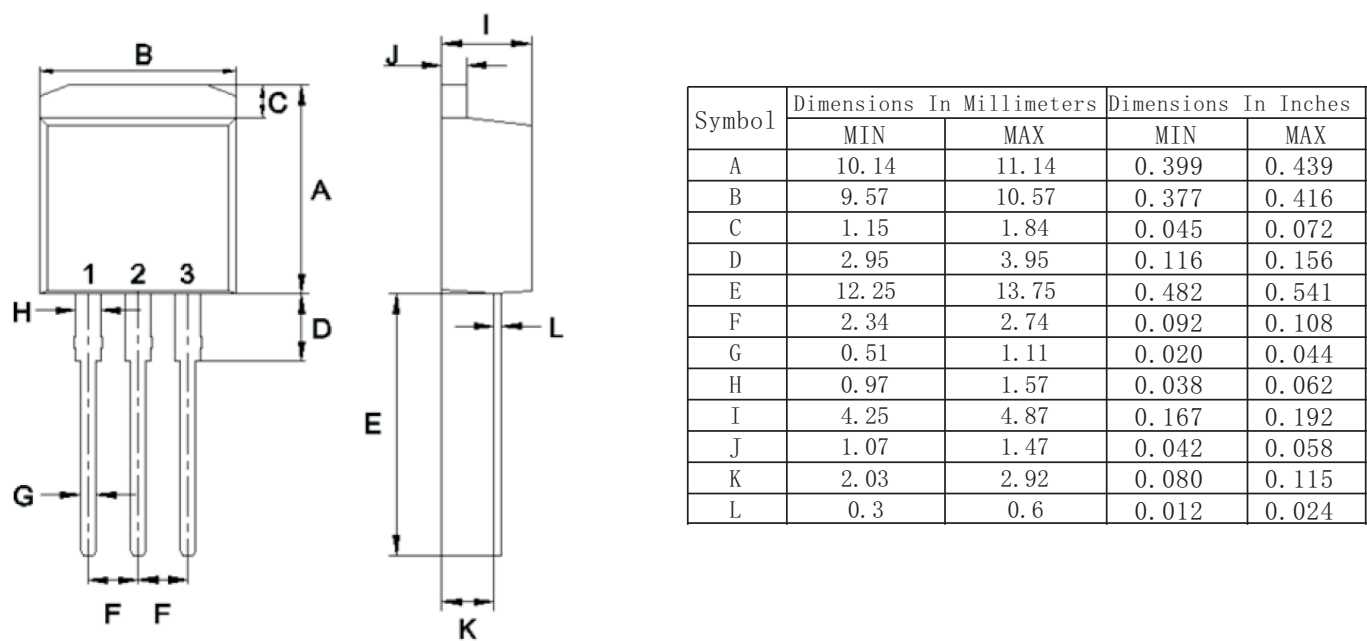
D30P10 Series

Dimensions

TO-263 PACKAGE OUTLINE DIMENSIONS



TO-262 PACKAGE OUTLINE DIMENSIONS

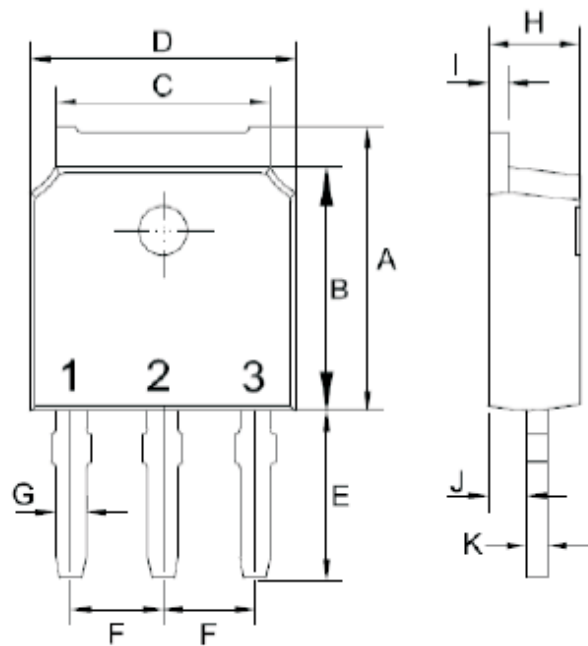




# D30P10 Series

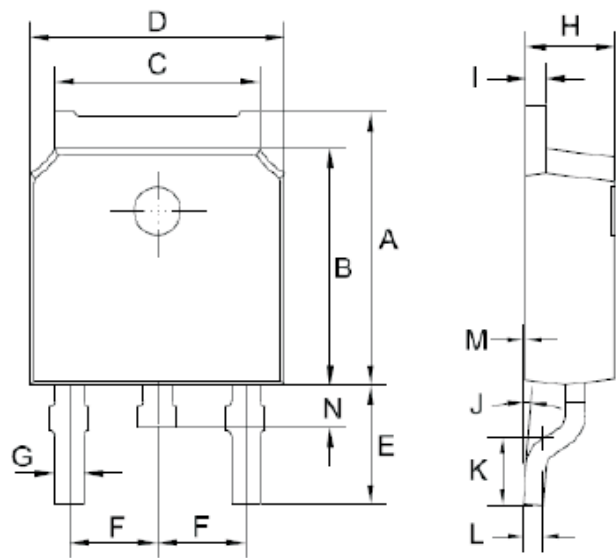
## Dimensions

### TO-251 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	6.85	7.25	0.270	0.285
B	5.8	6.3	0.228	0.248
C	5	5.53	0.197	0.218
D	6.3	6.8	0.248	0.268
E	3.5	4.35	0.138	0.171
F	2.19	2.39	0.086	0.094
G	0.45	0.85	0.018	0.033
H	2.2	2.4	0.087	0.094
I	0.41	0.61	0.016	0.024
J	0.71	1.31	0.028	0.052
K	0.41	0.61	0.016	0.024

### TO-252 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	6.85	7.25	0.270	0.285
B	5.8	6.3	0.228	0.248
C	5	5.53	0.197	0.218
D	6.3	6.8	0.248	0.268
E	2.6	3.3	0.102	0.130
F	2.19	2.39	0.086	0.094
G	0.45	0.85	0.018	0.033
H	2.2	2.4	0.087	0.094
I	0.41	0.61	0.016	0.024
J	0	8	0	8
K	1.45	1.85	0.057	0.073
L	0.41	0.61	0.016	0.024
M	0	0.12	0.000	0.005
N	0.6	1	0.024	0.039

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